# 74LVC244A-Q100; 74LVCH244A-Q100

Quad buffer/line driver; 3-state

Rev. 2 — 13 August 2013

**Product data sheet** 

### 1. General description

The 74LVC244A-Q100; 74LVCH244A-Q100 is an octal non-inverting buffer/line driver with 3-state outputs. The 3-state outputs are controlled by the output enable inputs 1OE and 2OE. A HIGH on nOE causes the outputs to assume a high-impedance OFF-state. Schmitt-trigger action at all inputs makes the circuit highly tolerant for slower input rise and fall times.

Inputs can be driven from either 3.3 V or 5.0 V devices. In 3-state operation, outputs can handle 5 V. These features allow the use of these devices as translators in a mixed 3.3 V and 5 V environment.

The 74LVCH244A-Q100 bus hold on data inputs eliminates the need for external pull-up resistors to hold unused inputs.

This product has been qualified to the Automotive Electronics Council (AEC) standard Q100 (Grade 1) and is suitable for use in automotive applications.

#### 2. Features and benefits

- Automotive product qualification in accordance with AEC-Q100 (Grade 1)
  - ◆ Specified from -40 °C to +85 °C and from -40 °C to +125 °C
- 5 V tolerant inputs/outputs for interfacing with 5 V logic
- Wide supply voltage range from 1.2 V to 3.6 V
- CMOS low-power consumption
- Direct interface with TTL levels
- Inputs accept voltages up to 5.5 V
- High-impedance when V<sub>CC</sub> = 0 V
- Bus hold on all data inputs (74LVCH244A-Q100 only)
- Complies with JEDEC standard:
  - ◆ JESD8-7A (1.65 V to 1.95 V)
  - JESD8-5A (2.3 V to 2.7 V)
  - ◆ JESD8-C/JESD36 (2.7 V to 3.6 V)
- ESD protection:
  - MIL-STD-883, method 3015 exceeds 2000 V
  - ♦ HBM JESD22-A114F exceeds 2000 V
  - $\bullet$  MM JESD22-A115-A exceeds 200 V (C = 200 pF, R = 0  $\Omega$ )
- Multiple package options

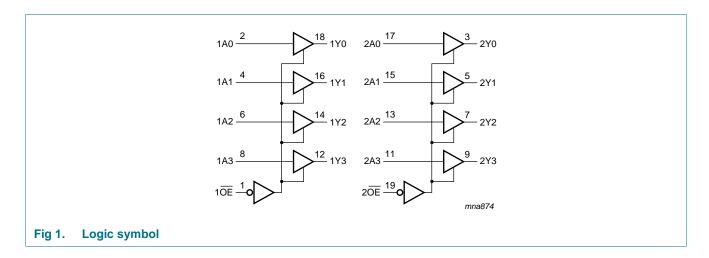


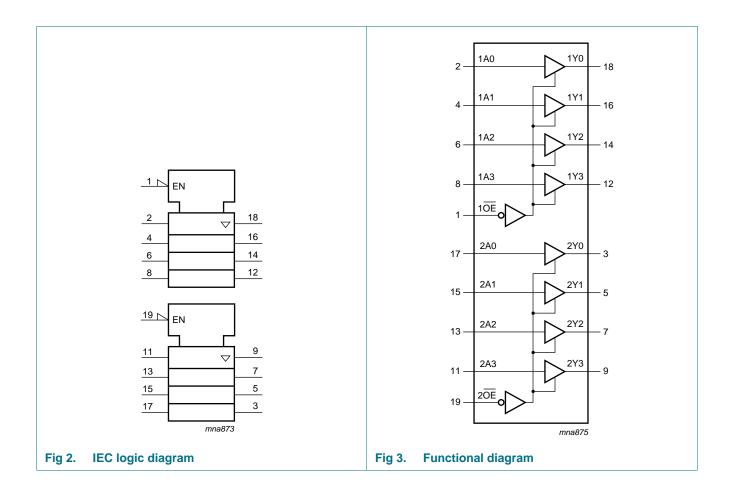
### 3. Ordering information

Table 1. Ordering information

Type number	Package				
	Temperature range	Name	Description	Version	
74LVC244AD-Q100	–40 °C to +125 °C	SO20	plastic small outline package; 20 leads;	SOT163-1	
74LVCH244AD-Q100			body width 7.5 mm		
74LVC244ADB-Q100	–40 °C to +125 °C	SSOP20	plastic shrink small outline package; 20 leads;	SOT339-1	
74LVCH244ADB-Q100			body width 5.3 mm		
74LVC244APW-Q100	–40 °C to +125 °C	TSSOP20	plastic thin shrink small outline package; 20	SOT360-1	
74LVCH244APW-Q100			leads; body width 4.4 mm		
74LVC244ABQ-Q100	–40 °C to +125 °C	DHVQFN20	plastic dual in-line compatible thermal enhanced	SOT764-1	
74LVCH244ABQ-Q100			very thin quad flat package; no leads; 20 terminals; body $2.5 \times 4.5 \times 0.85$ mm		

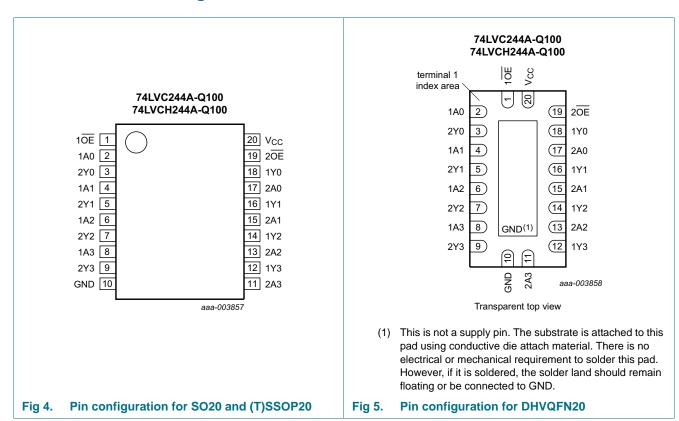
### 4. Functional diagram





### 5. Pinning information

#### 5.1 Pinning



#### 5.2 Pin description

Table 2. Pin description

	•	
Symbol	Pin	Description
10E, 20E	1, 19	output enable input (active low)
1A0, 1A1, 1A2, 1A3	2, 4, 6, 8	data input
2Y0, 2Y1, 2Y2, 2Y3	3, 5, 7, 9	data output
GND	10	ground (0 V)
2A0, 2A1, 2A2, 2A3	17, 15, 13, 11	data input
1Y0, 1Y1, 1Y2, 1Y3,	18, 16, 14, 12	data output
V <sub>CC</sub>	20	supply voltage

### 6. Functional description

Table 3. Function table [1]

Control	Input	Output
nOE	nAn	nYn
L	L	L
L	Н	Н
Н	X	Z

<sup>[1]</sup> H = HIGH voltage level; L = LOW voltage level; X = don't care; Z = high-impedance OFF-state.

### 7. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134). Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	Min	Max	Unit
$V_{CC}$	supply voltage		-0.5	+6.5	V
I <sub>IK</sub>	input clamping current	V <sub>I</sub> < 0 V	-50	-	mA
VI	input voltage		<u>[1]</u> –0.5	+6.5	V
I <sub>OK</sub>	output clamping current	$V_O > V_{CC}$ or $V_O < 0 V$	-	±50	mA
Vo	output voltage	output HIGH or LOW	<u>[2]</u> −0.5	$V_{CC} + 0.5$	V
		output 3-state	<u>[2]</u> −0.5	+6.5	V
I <sub>O</sub>	output current	$V_O = 0 V \text{ to } V_{CC}$	-	±50	mA
I <sub>CC</sub>	supply current		-	100	mA
I <sub>GND</sub>	ground current		-100	-	mA
T <sub>stg</sub>	storage temperature		-65	+150	°C
P <sub>tot</sub>	total power dissipation	$T_{amb} = -40 ^{\circ}\text{C} \text{ to } +125 ^{\circ}\text{C}$	[3] _	500	mW

<sup>[1]</sup> The minimum input voltage ratings may be exceeded if the input current ratings are observed.

<sup>[2]</sup> The output voltage ratings may be exceeded if the output current ratings are observed.

<sup>[3]</sup> For SO20 packages: above 70 °C derate linearly with 8 mW/K.
For (T)SSOP20 packages: above 60 °C derate linearly with 5.5 mW/K.
For DHVQFN20 packages: above 60 °C derate linearly with 4.5 mW/K.

### 8. Recommended operating conditions

Table 5. Recommended operating conditions

Symbol	Parameter	Conditions	Min	Тур	Max	Unit
$V_{CC}$	supply voltage		1.65	-	3.6	V
		functional	1.2	-	3.6	V
VI	input voltage		0	-	5.5	V
Vo	output voltage	output HIGH or LOW	0	-	$V_{CC}$	V
		output 3-state	0	-	5.5	V
T <sub>amb</sub>	ambient temperature	in free air	-40	-	+125	°C
Δt/ΔV	input transition rise and fall rate	$V_{CC} = 1.2 \text{ V to } 2.7 \text{ V}$	0	-	20	ns/V
		$V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$	0	-	10	ns/V

#### 9. Static characteristics

Table 6. Static characteristics

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions	-40	°C to +8	35 °C	–40 °C to	o +125 °C	Unit
			Min	Typ[1]	Max	Min	Max	
$V_{IH}$	HIGH-level	V <sub>CC</sub> = 1.2 V	1.08	-	-	1.08	-	V
	input voltage	$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$	$0.65 \times V_{CC}$	-	-	0.65 × V <sub>CC</sub>	-	V
		V <sub>CC</sub> = 2.3 V to 2.7 V	1.7	-	-	1.7	-	V
	V <sub>CC</sub> = 2.7 V to 3.6 V	2.0	-	-	2.0	-	V	
V <sub>IL</sub>	LOW-level	V <sub>CC</sub> = 1.2 V	-	-	0.12	-	0.12	V
input voltage	V <sub>CC</sub> = 1.65 V to 1.95 V	-	-	$0.35 \times V_{CC}$	-	$0.35 \times V_{CC}$	V	
		V <sub>CC</sub> = 2.3 V to 2.7 V	-	-	0.7	-	0.7	V
		V <sub>CC</sub> = 2.7 V to 3.6 V	-	-	8.0	-	0.8	V
V <sub>OH</sub> HIGH-level output voltage	$V_I = V_{IH}$ or $V_{IL}$							
	•	$I_O = -100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	V <sub>CC</sub> - 0.2	-	-	V <sub>CC</sub> - 0.3	-	V
		$I_{O} = -4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	1.2	-	-	1.05	-	V
		$I_{O} = -8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	1.8	-	-	1.65	-	V
		$I_{O} = -12 \text{ mA}; V_{CC} = 2.7 \text{ V}$	2.2	-	-	2.05	-	V
		$I_{O} = -18 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.4	-	-	2.25	-	V
		$I_{O} = -24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	2.2	-	-	2.0	-	V
V <sub>OL</sub>	LOW-level	$V_I = V_{IH}$ or $V_{IL}$						
	output voltage	$I_O = 100 \mu A;$ $V_{CC} = 1.65 \text{ V to } 3.6 \text{ V}$	-	-	0.2	-	0.3	V
		$I_{O} = 4 \text{ mA}; V_{CC} = 1.65 \text{ V}$	-	-	0.45	-	0.65	V
		$I_{O} = 8 \text{ mA}; V_{CC} = 2.3 \text{ V}$	-	-	0.6	-	0.8	V
		$I_{O}$ = 12 mA; $V_{CC}$ = 2.7 V	-	-	0.4	-	0.6	V
		$I_O = 24 \text{ mA}; V_{CC} = 3.0 \text{ V}$	-	-	0.55	-	0.8	V

 Table 6.
 Static characteristics ...continued

At recommended operating conditions. Voltages are referenced to GND (ground = 0 V).

Symbol	Parameter	Conditions		-40	0 °C to +85	°C	–40 °C to	Unit	
				Min	Typ[1]	Max	Min	Max	
l <sub>l</sub>	input leakage current	V <sub>I</sub> = 5.5 V or GND; V <sub>CC</sub> = 3.6 V	[2]	-	±0.1	±5	-	±20	μΑ
l <sub>OZ</sub>	OFF-state output current	$V_I = V_{IH}$ or $V_{IL}$ ; $V_O = 5.5 \text{ V or GND}$ ; $V_{CC} = 3.6 \text{ V}$	[2]	-	±0.1	±5	-	±20	μΑ
I <sub>OFF</sub>	power-off leakage current	$V_{I}$ or $V_{O} = 5.5 \text{ V}$ ; $V_{CC} = 0.0 \text{ V}$		-	±0.1	±10	-	±20	μΑ
I <sub>CC</sub>	supply current	$V_I = V_{CC}$ or GND; $I_O = 0$ A; $V_{CC} = 3.6 \text{ V}$		-	0.1	10	-	40	μА
Δl <sub>CC</sub>	additional supply current	per input pin; $V_I = V_{CC} - 0.6 \text{ V}; I_O = 0 \text{ A};$ $V_{CC} = 2.7 \text{ V to } 3.6 \text{ V}$		-	5	500	-	5000	μΑ
C <sub>I</sub>	input capacitance			-	4.0	-	-	-	pF
I <sub>BHL</sub>	bus hold	$V_{CC} = 1.65 \text{ V}; V_I = 0.58 \text{ V}$	[3][4]	10	-	-	10	-	μΑ
	LOW current	$V_{CC} = 2.3 \text{ V}; V_I = 0.7 \text{ V}$		30	-	-	25	-	μΑ
		$V_{CC} = 3.0 \text{ V}; V_I = 0.8 \text{ V}$		75	-	-	60	-	μΑ
I <sub>BHH</sub>	bus hold	$V_{CC} = 1.65 \text{ V}; V_I = 1.07 \text{ V}$	[3][4]	-10	-	-	-10	-	μΑ
	HIGH current	$V_{CC} = 2.3 \text{ V}; V_I = 1.7 \text{ V}$		-30	-	-	-25	-	μΑ
	Carront	$V_{CC} = 3.0 \text{ V}; V_I = 2.0 \text{ V}$		<b>-75</b>	-	-	-60	-	μΑ
$I_{BHLO}$	bus hold	V <sub>CC</sub> = 1.95 V	[3][5]	200	-	-	200	-	μΑ
	LOW overdrive	$V_{CC} = 2.7 \text{ V}$		300	-	-	300	-	μΑ
	current	$V_{CC} = 3.6 \text{ V}$		500	-	-	500	-	μΑ
I <sub>BHHO</sub>	bus hold	V <sub>CC</sub> = 1.95 V	[3][5]	-200	-	-	-200	-	μΑ
	HIGH	V <sub>CC</sub> = 2.7 V		-300	-	-	-300	-	μΑ
	overdrive current	V <sub>CC</sub> = 3.6 V		-500	-	-	-500	-	μΑ

<sup>[1]</sup> All typical values are measured at  $V_{CC}$  = 3.3 V (unless stated otherwise) and  $T_{amb}$  = 25 °C.

<sup>[2]</sup> The bus hold circuit is switched off when  $V_{I} > V_{CC}$  allowing 5.5 V on the input terminal.

<sup>[3]</sup> Valid for data inputs of bus hold parts only (74LVCH244A-Q100). Note that control inputs do not have a bus hold circuit.

<sup>[4]</sup> The specified sustaining current at the data input holds the input below the specified V<sub>I</sub> level.

<sup>[5]</sup> The specified overdrive current at the data input forces the data input to the opposite input state.

### 10. Dynamic characteristics

Table 7. Dynamic characteristics

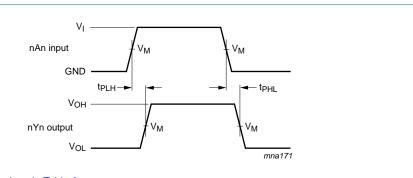
Voltages are referenced to GND (ground = 0 V). For test circuit see Figure 8.

Symbol	Parameter	Conditions		-40	°C to +8	5 °C	-40 °C to	+125 °C	Unit
				Min	Typ[1]	Max	Min	Max	
t <sub>pd</sub>	propagation	nAn to nYn; see Figure 6	[2]		'		1	1	
	delay	V <sub>CC</sub> = 1.2 V		-	17.0	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.5	6.4	13.7	1.5	15.8	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.0	3.4	7.1	1.0	8.2	ns
		V <sub>CC</sub> = 2.7 V		1.5	3.4	6.9	1.5	9.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	2.9	5.9	1.5	7.5	ns
t <sub>en</sub>	enable time	nOE to nYn; see Figure 7	[2]						
		V <sub>CC</sub> = 1.2 V		-	24.0	-	-	-	ns
		V <sub>CC</sub> = 1.65 V to 1.95 V		1.5	7.0	17.3	1.5	20.0	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		1.5	3.9	9.5	1.5	11.0	ns
		V <sub>CC</sub> = 2.7 V		1.5	4.1	8.6	1.5	11.0	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.0	3.2	7.6	1.0	9.5	ns
t <sub>dis</sub>	disable time	nOE to nYn; see Figure 7	[2]						
		V <sub>CC</sub> = 1.2 V		-	9.0	-	-	-	ns
		$V_{CC} = 1.65 \text{ V to } 1.95 \text{ V}$		2.2	4.5	9.8	2.2	11.3	ns
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		0.5	3.6	5.5	0.5	6.4	ns
		$V_{CC} = 2.7 \text{ V}$		1.5	3.3	6.8	1.5	8.5	ns
		$V_{CC} = 3.0 \text{ V to } 3.6 \text{ V}$		1.5	3.1	5.8	1.5	7.5	ns
t <sub>sk(o)</sub>	output skew time		[3]	-	-	1.0	-	1.5	ns
$C_{PD}$	power	per input; $V_I = GND$ to $V_{CC}$	<u>[4]</u>						
	dissipation capacitance	V <sub>CC</sub> = 1.65 V to 1.95 V		-	6.4	-	-	-	pF
	capacitatice	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		-	9.6	-	-	-	pF
		V <sub>CC</sub> = 3.0 V to 3.6 V		-	12.5	-	-	-	pF

- [1] Typical values are measured at  $T_{amb}$  = 25 °C and  $V_{CC}$  = 1.2 V, 1.8 V, 2.5 V, 2.7 V, and 3.3 V respectively.
- [2]  $t_{pd}$  is the same as  $t_{PLH}$  and  $t_{PHL}$ .
  - $t_{\text{en}}$  is the same as  $t_{\text{PZL}}$  and  $t_{\text{PZH}}.$
  - $t_{dis}$  is the same as  $t_{PLZ}$  and  $t_{PHZ}$ .
- [3] Skew between any two outputs of the same package switching in the same direction. This parameter is guaranteed by design.
- [4]  $C_{PD}$  is used to determine the dynamic power dissipation ( $P_D$  in  $\mu W$ ).
  - $P_D = C_{PD} \times V_{CC}{}^2 \times f_i \times N + \Sigma (C_L \times V_{CC}{}^2 \times f_o) \text{ where:}$
  - $f_i$  = input frequency in MHz;  $f_o$  = output frequency in MHz
  - $C_L$  = output load capacitance in pF
  - V<sub>CC</sub> = supply voltage in Volts
  - N = number of inputs switching
  - $\Sigma(C_L \times V_{CC}^2 \times f_0)$  = sum of the outputs.

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#### 11. AC waveforms



Measurement points are given in Table 8.

Logic levels: V<sub>OL</sub> and V<sub>OH</sub> are typical output voltage levels that occur with the output load.

Fig 6. The input (nAn) to output (nYn) propagation delays

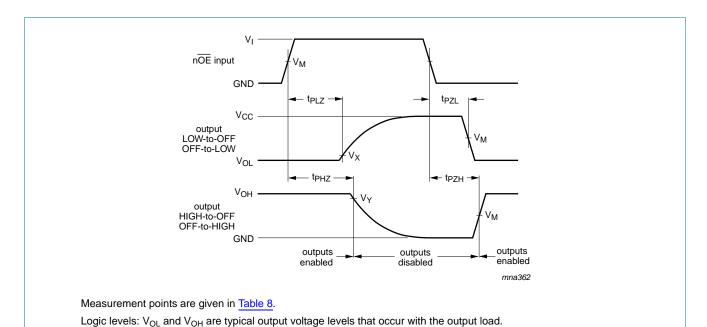
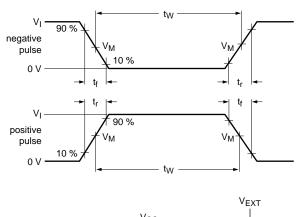
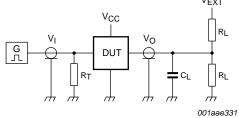


Fig 7. 3-state enable and disable times.

Table 8. Measurement points

Supply voltage	Input		Output	Output								
V <sub>CC</sub>	VI	V <sub>M</sub>	V <sub>M</sub>	V <sub>X</sub>	V <sub>Y</sub>							
1.2 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	$V_{OH}-0.15\ V$							
1.65 V to 1.95 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V							
2.3 V to 2.7 V	$V_{CC}$	$0.5 \times V_{CC}$	$0.5 \times V_{CC}$	V <sub>OL</sub> + 0.15 V	V <sub>OH</sub> – 0.15 V							
2.7 V	2.7 V	1.5 V	1.5 V	$V_{OL}$ + 0.3 $V$	$V_{OH} - 0.3 V$							
3.0 V to 3.6 V	2.7 V	1.5 V	1.5 V	$V_{OL} + 0.3 V$	$V_{OH} - 0.3 V$							





Test data is given in Table 9.

Definitions for test circuit:

R<sub>L</sub> = Load resistance.

 $C_L$  = Load capacitance including jig and probe capacitance.

 $R_T$  = Termination resistance should be equal to output impedance  $Z_0$  of the pulse generator.

V<sub>EXT</sub> = External voltage for measuring switching times.

Fig 8. Test circuit for measuring switching times

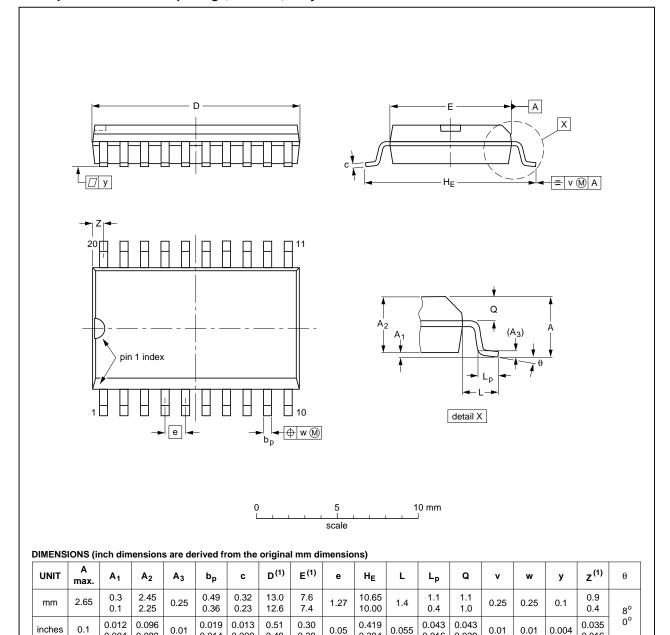
Table 9. Test data

Supply voltage	Input		Load		V <sub>EXT</sub>	V <sub>EXT</sub>				
	VI	t <sub>r</sub> , t <sub>f</sub>	CL	$R_L$	t <sub>PLH</sub> , t <sub>PHL</sub>	$t_{PLZ}, t_{PZL}$	t <sub>PHZ</sub> , t <sub>PZH</sub>			
1.2 V	$V_{CC}$	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND			
1.65 V to 1.95 V	$V_{CC}$	≤ 2 ns	30 pF	1 kΩ	open	$2\times V_{CC}$	GND			
2.3 V to 2.7 V	$V_{CC}$	≤ 2 ns	30 pF	$500 \Omega$	open	$2\times V_{CC}$	GND			
2.7 V	2.7 V	≤ 2.5 ns	50 pF	$500 \Omega$	open	$2\times V_{CC}$	GND			
3.0 V to 3.6 V	2.7 V	≤ 2.5 ns	50 pF	$500 \Omega$	open	$2\times V_{CC}$	GND			

### 12. Package outline

#### SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



#### Note

1. Plastic or metal protrusions of 0.15 mm (0.006 inch) maximum per side are not included.

0.009

OUTLINE		REFER	EUROPEAN	ISSUE DATE		
VERSION	VERSION IEC JEDEC JEITA			PROJECTION	ISSUE DATE	
SOT163-1	075E04	MS-013				<del>99-12-27</del> 03-02-19

0.394

0.016

0.039

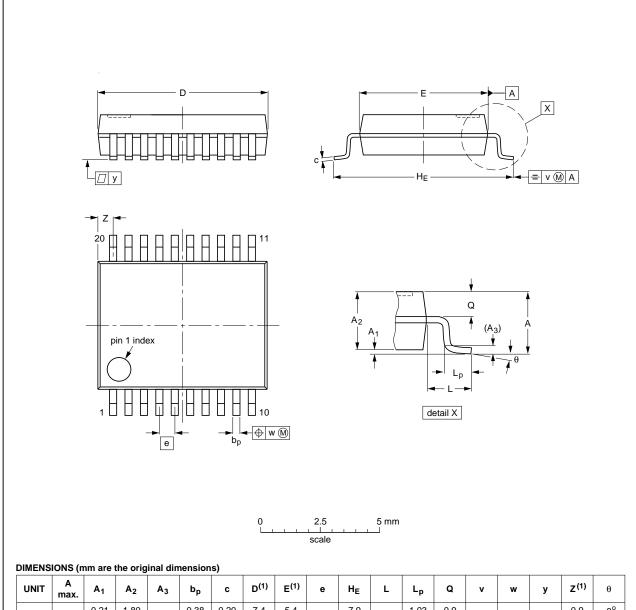
Fig 9. Package outline SOT163-1 (SO20)

0.089

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#### SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



UNIT	A max.	A <sub>1</sub>	A <sub>2</sub>	A <sub>3</sub>	bp	C	D <sup>(1)</sup>	E <sup>(1)</sup>	е	HE	L	Lp	Q	٧	w	у	Z <sup>(1)</sup>	θ
mm	2	0.21 0.05	1.80 1.65	0.25	0.38 0.25	0.20 0.09	7.4 7.0	5.4 5.2	0.65	7.9 7.6	1.25	1.03 0.63	0.9 0.7	0.2	0.13	0.1	0.9 0.5	8° 0°

#### Note

1. Plastic or metal protrusions of 0.2 mm maximum per side are not included.

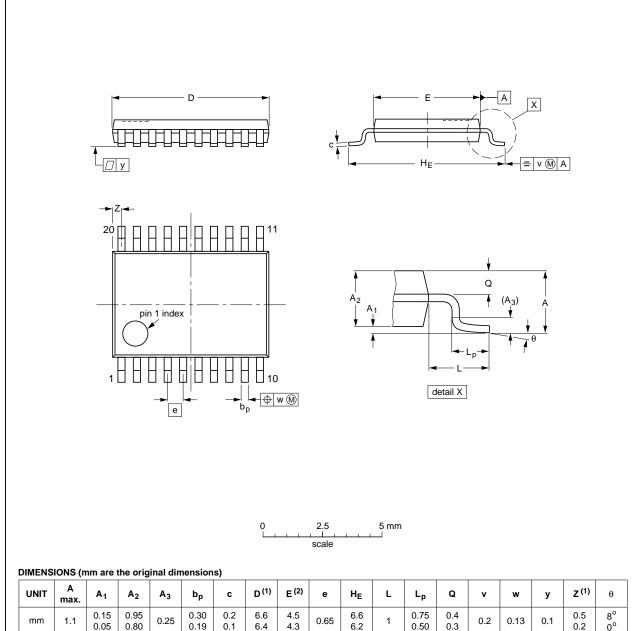
OUTLINE VERSION	REFERENCES			EUROPEAN	ISSUE DATE		
	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE	
SOT339-1		MO-150				<del>99-12-27</del> 03-02-19	
							4

Fig 10. Package outline SOT339-1 (SSOP20)

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#### TSSOP20: plastic thin shrink small outline package; 20 leads; body width 4.4 mm

SOT360-1



- 1. Plastic or metal protrusions of 0.15 mm maximum per side are not included.
- 2. Plastic interlead protrusions of 0.25 mm maximum per side are not included.

OUTLINE	REFERENCES				EUROPEAN	ISSUE DATE
VERSION	IEC	JEDEC	JEITA		PROJECTION	ISSUE DATE
SOT360-1		MO-153				<del>99-12-27</del> 03-02-19
	•	•	•	•		•

Fig 11. Package outline SOT360-1 (TSSOP20)

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DHVQFN20: plastic dual in-line compatible thermal enhanced very thin quad flat package; no leads; 20 terminals; body 2.5 x 4.5 x 0.85 mm SOT764-1

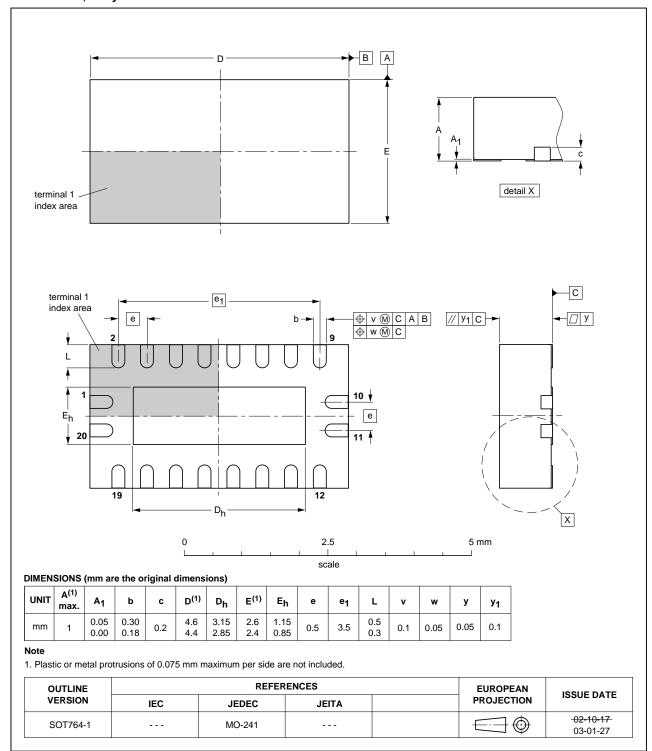


Fig 12. Package outline SOT764-1 (DHVQFN20)

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### 13. Abbreviations

#### Table 10. Abbreviations

Acronym	Description	
CDM	Charged Device Model	
CMOS	Complementary Metal Oxide Semiconductor	
DUT	Device Under Test	
ESD	ElectroStatic Discharge	
НВМ	Human Body Model	
MM	Machine Model	
TTL	Transistor-Transistor Logic	
MIL	Military	

## 14. Revision history

#### Table 11. Revision history

Document ID	Release date	Data sheet status	Change notice	Supersedes
74LVC_LVCH244A_Q100 v.2	20130813	Product data sheet	-	74LVC_LVCH244A_Q100 v.1
Modifications: • 74LVC244ADB-Q100 and 74LVCH244DB-Q100 added.				
74LVC_LVCH244A_Q100 v.1	20120823	Product data sheet	-	-

### 15. Legal information

#### 15.1 Data sheet status

Document status[1][2]	Product status[3]	Definition
Objective [short] data sheet	Development	This document contains data from the objective specification for product development.
Preliminary [short] data sheet	Qualification	This document contains data from the preliminary specification.
Product [short] data sheet	Production	This document contains the product specification.

- [1] Please consult the most recently issued document before initiating or completing a design.
- [2] The term 'short data sheet' is explained in section "Definitions"
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